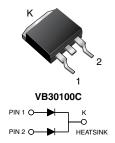
VB30100C-M3, VB30100CHM3

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.455 \text{ V}$ at $I_F = 5 \text{ A}$





PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I _{F(AV)}	2 x 15 A			
V_{RRM}	100 V			
I _{FSM}	160 A			
V _F at I _F = 15 A	0.63 V			
T _J max.	150 °C			
Diode variations	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation

· Low thermal resistance

ROHS COMPLIANT HALOGEN FREE

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified available:
 - Automotive ordering code P/NHM3
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER Maximum repetitive peak reverse voltage		SYMBOL	VB30100C	UNIT V
		V_{RRM}	100	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	30	^
	per diode		15	A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	160	А
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C	V _F	0.516	-	V
	$I_F = 7.5 A$			0.576	-	
	I _F = 15 A			0.734	0.80	
	I _F = 5 A	T _A = 125 °C		0.455	-	
	I _F = 7.5 A			0.522	-	
	I _F = 15 A			0.627	0.68	
Reverse current per diode (2)	V _R = 70 V	T _A = 25 °C	I _R	7.2	-	μΑ
	v _R = 70 v	T _A = 125 °C		8.0	-	mA
	V 100 V	T _A = 25 °C		65	500	μΑ
	V _R = 100 V	T _A = 125 °C		20	35	mA

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VB30100C	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	2.5	°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB30100C-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VB30100C-M3/8W	1.39	8W	800/reel	Tape and reel	
TO-263AB	VB30100CHM3/I (1)	1.39	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

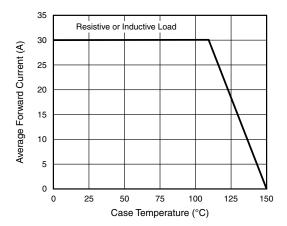


Fig. 1 - Forward Current Derating Curve

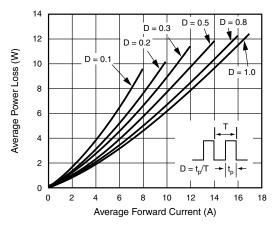


Fig. 2 - Forward Power Loss Characteristics Per Diode

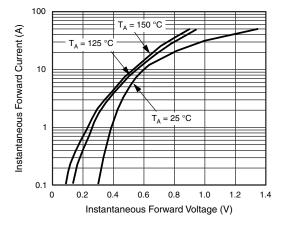


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

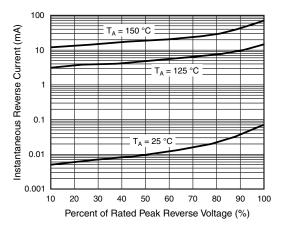


Fig. 4 - Typical Reverse Characteristics Per Diode

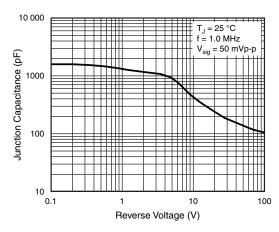


Fig. 5 - Typical Junction Capacitance

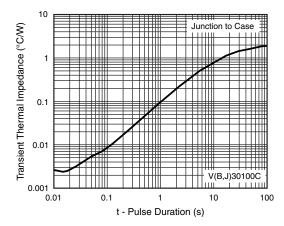
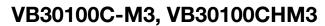


Fig. 6 - Typical Transient Thermal Impedance Per Diode

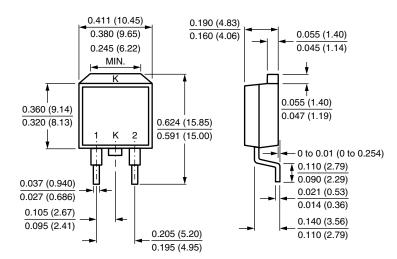




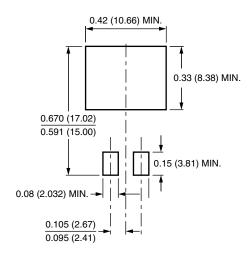
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-263AB



Mounting Pad Layout





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